

Schottky Barrier Diode

PIN	DESCRIPTION
1	Cathode
2	Anode



Simplified outline SOD-123 and symbol

MARKING: G2*

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	RB161M-20	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	V
Maximum RMS voltage	V_{RMS}	14	V
Maximum DC Blocking Voltage	V_{DC}	20	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1.0	A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30	A
Max Instantaneous Forward Voltage at 1 A	V_F	0.55	V
Maximum DC Reverse Current $T_a = 25^{\circ}C$ at Rated DC Reverse Voltage $T_a = 100^{\circ}C$	I_R	0.3 10	mA
Typical Junction Capacitance ⁽¹⁾	C_j	110	pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	100	°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150	°C
Storage Temperature Range	T_{stg}	-55 ~ +150	°C

Typical Characteristics

Fig.1 Forward Current Derating Curve

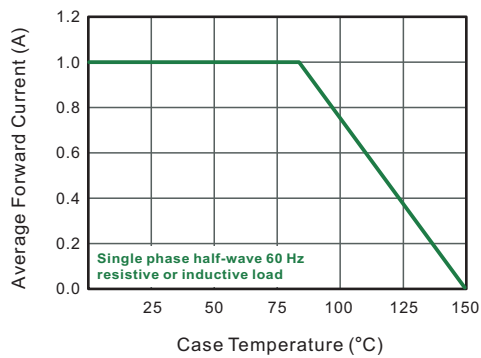


Fig.2 Typical Reverse Characteristics

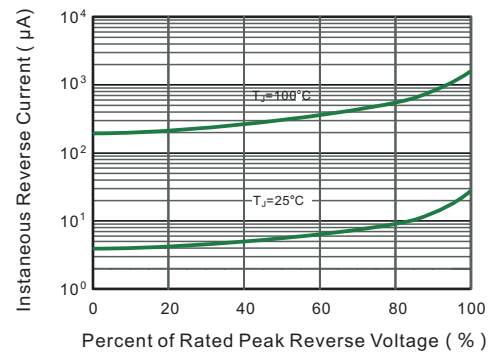


Fig.3 Typical Forward Characteristic

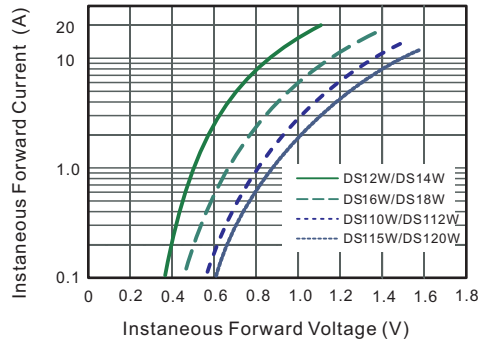


Fig.4 Typical Junction Capacitance

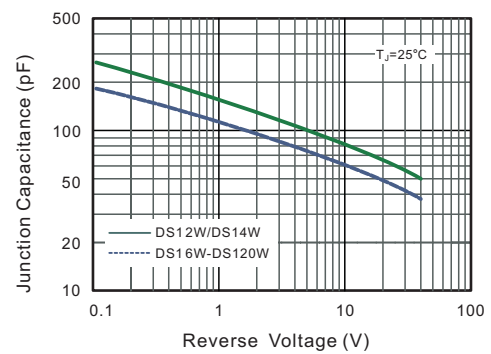


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

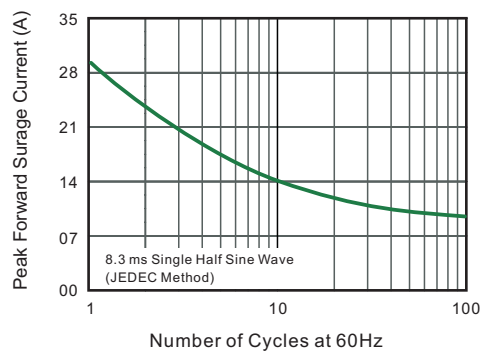
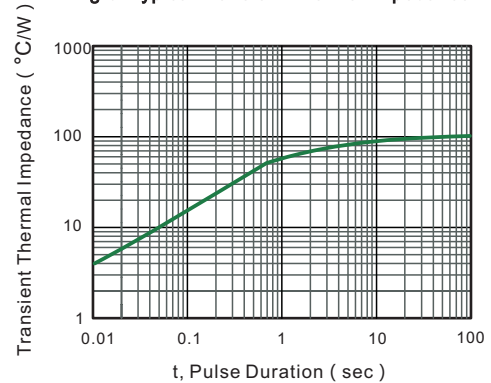
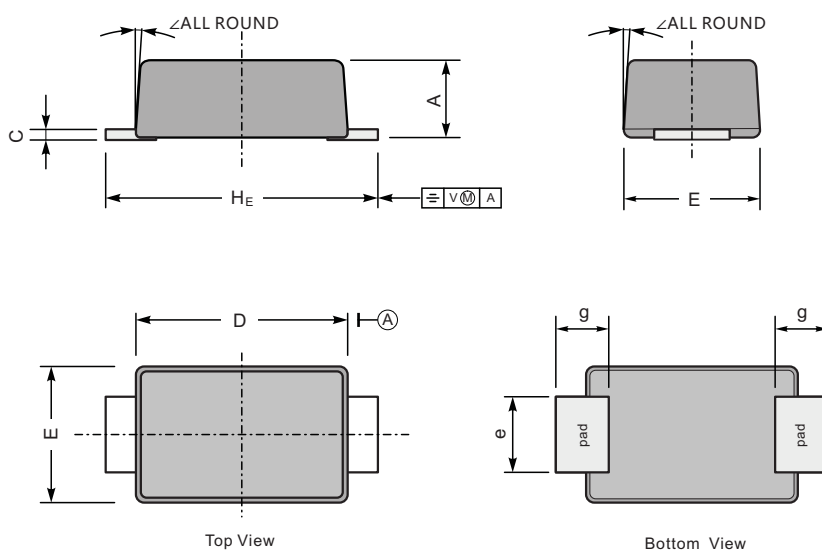


Fig.6- Typical Transient Thermal Impedance



PACKAGE OUTLINE



UNIT		A	C	D	E	e	g	H_E	$\angle$
mm	max	1.1	0.20	2.9	1.9	1.1	0.9	3.8	7°
	min	0.9	0.12	2.6	1.7	0.8	0.7	3.5	
mil	max	43	7.9	114	75	43	35	150	
	min	35	4.7	102	67	31	28	138	